NSN 5961-01-294-6705

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-6705 **Inclosure Material:** Metal **Overall Length:** Between 5.035 inches and 5.515 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and burn in **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage and 1200.0 nonrepetitive peak reverse voltage and 1000.0 reverse voltage, dc **Current Rating Per Characteristic:** 125.00 amperes drain current megahertz and 2500.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug **Specification Data:** 53711-5974746-1 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0